

Features

- · ESD Protected Up To 2KV (HBM)
- · Low Threshold Voltage
- Moisture Sensitivity Level 3
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

N-Channel MOSFET

Maximum Ratings

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Maximum Thermal Resistance: 382°C/W Junction to Ambient^(Note 2)

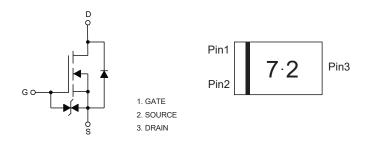
Parameter		Symbol	Rating	Unit	
Drain -source Voltage		V _{DS}	60	V	
Gate -Source Voltage		V _{GS}	±20	V	
Drain Current-Continuous	T _A =25°C		0.26	А	
	T _A =70°C	I _D	0.21		
Pulsed Drain Current		I _{DM}	1.04	А	
Power Dissipation		P _D	0.33	W	

Note:

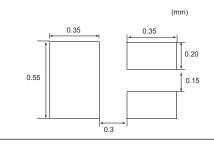
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

DIMENSIONS						
DIM	INCHES		MM		NOTE	
	MIN	MAX	MIN	MAX	NOTE	
Α	0.017	0.022	0.42	0.55		
A1	0.000	0.002	0.00	0.05		
b	0.018	0.022	0.45	0.55		
b1	0.004	0.008	0.10	0.20		
С	0.005	0.007	0.12	0.18		
D	0.037	0.041	0.95	1.05		
Е	0.022	0.026	0.55	0.65		
E1	0.006	0.010	0.15	0.25		
е	0.026	BSC	0.65	BSC		
L	0.008	0.012	0.20	0.30		
L1	0.0002 REF		0.05	REF		

Internal Structure and Marking Code



Suggested Solder Pad Layout





Electrical Characteristics @ 25°C (Unless Otherwise Specified)

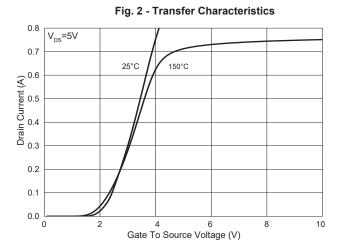
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics	<u> </u>			1	I		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} =0V, I_{D} =250 μ A	60			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±10	μA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μA	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.5	2.5	V	
Drain-Source On-Resistance	Б	V _{GS} =10V, I _D =300mA		1.8	2.5	Ω	
Diani-Source On-Nesistance	$R_{DS(on)}$	V _{GS} =4.5V, I _D =200mA		2.0	3.0		
Forward Transconductance	9 FS	V _{DS} =10V, I _D =200mA		300		mS	
Gate Resistance	R _g	f=1 MHz, Open drain		100		Ω	
Diode Characteristics							
Continuous Body Diode Current	Is				0.26	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =300mA			1.2	V	
Reverse Recovery Time	t _{rr}	1 -0 2 A d 1 /dt-400 A /		10		ns	
Reverse Recovery Charge	Q _{rr}	I_F =0.3A, dI_F/dt =100A/ μ s		2.6		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			15			
Output Capacitance	C _{oss}	V_{DS} =25V, V_{GS} =0V,f=1MHz		3		pF	
Reverse Transfer Capacitance	C _{rss}			2			
Total Gate Charge	Q_g			0.9			
Gate-Source Charge	Q_{gs}	$V_{DS} = 30V, V_{GS} = 10V, I_{D} = 0.3A$		0.15		nC	
Gate-Drain Charge	Q_{gd}			0.25			
Turn-On Delay Time	t _{d(on)}			3			
Turn-On Rise Time	t _r	V _{DD} =50V, V _{GS} =10V		3.8		,	
Turn-Off Delay Time	$t_{d(off)}$, $R_G = 50\Omega$, $I_D = 0.3A$		10		ns -	
Turn-Off Fall Time	t _f			30			

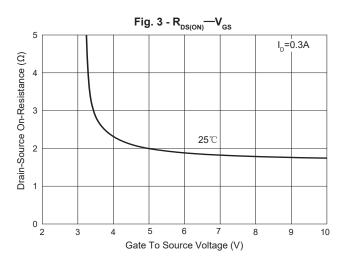


Curve Characteristics

Fig.1 - Typical Output Characteristics 8.0

Drain Current (A) 8.0 8.0 Vgs=10V,9V,8V,7V,6V,5V,4.5V,4V,3.5V,3V,2.5V 0.2 0.0 0 5 1 2 3 4 Drain To Source Voltage (V)





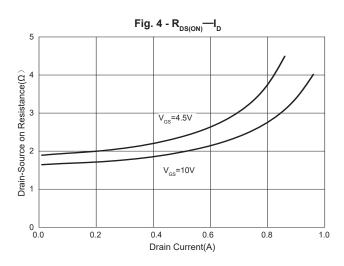


Fig. 5 - Capacitance Characteristics

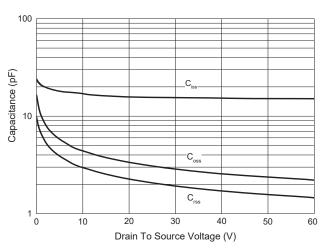
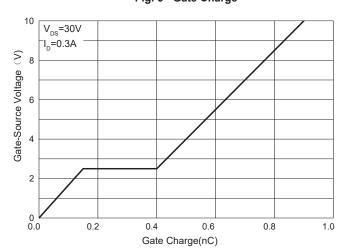
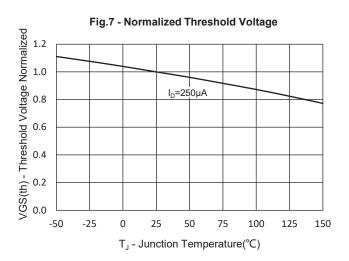


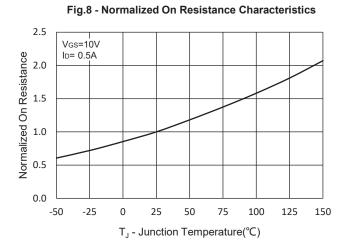
Fig. 6 - Gate Charge

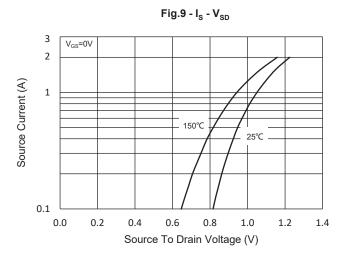


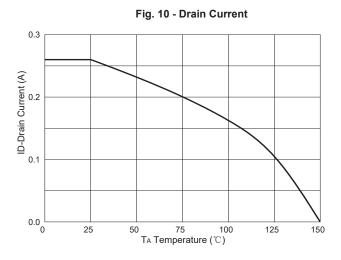


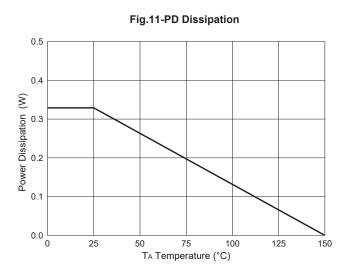
Curve Characteristics







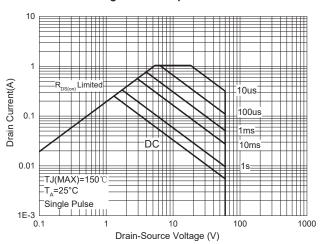


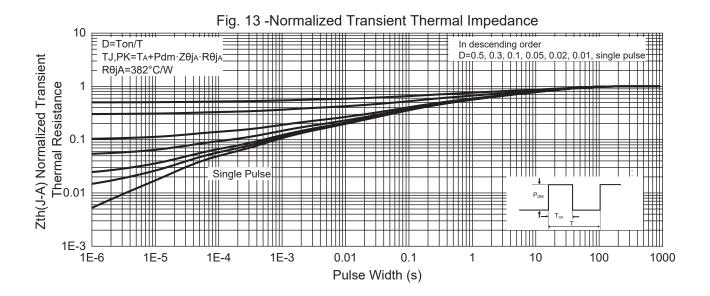




Curve Characteristics









Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 10Kpcs/Reel	
Part Number-TPQ3	Tape&Reel: 10Kpcs/Reel	

For packaging details, go to our website at https://www.mccsemi.com/pdf/productpackaging/DFN1006-3%20Package.pdf

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